

MOSFETs Silicon N-Channel MOS (U-MOSIII)

# SSM6N77FE

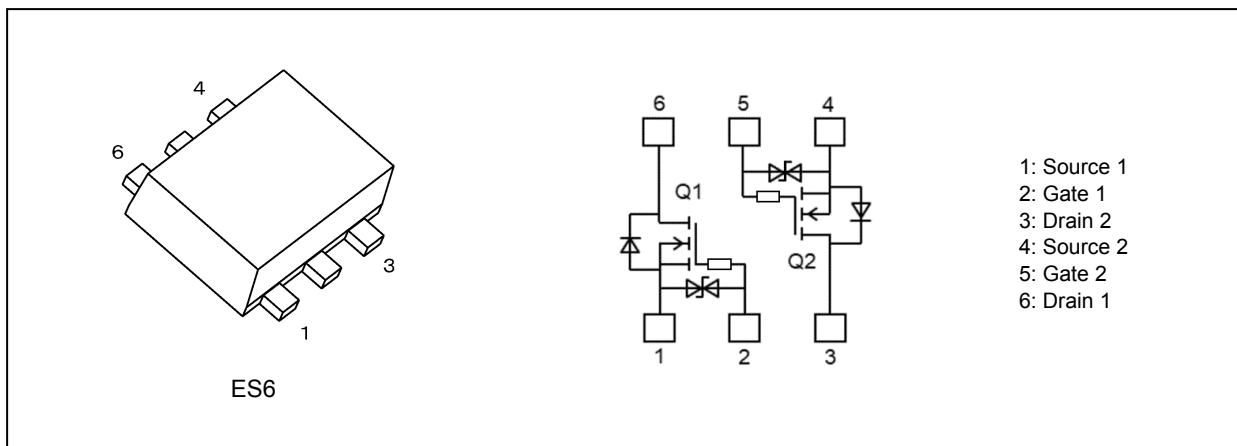
## 1. Applications

- High-Speed Switching
- Analog Switches

## 2. Features

- (1) 1.5 V gate drive voltage.
- (2) Low drain-source on-resistance
  - $R_{DS(ON)} = 5.60 \Omega$  (max) (@ $V_{GS} = 1.5 \text{ V}$ ,  $I_D = 10 \text{ mA}$ )
  - $R_{DS(ON)} = 4.05 \Omega$  (max) (@ $V_{GS} = 1.8 \text{ V}$ ,  $I_D = 20 \text{ mA}$ )
  - $R_{DS(ON)} = 3.02 \Omega$  (max) (@ $V_{GS} = 2.5 \text{ V}$ ,  $I_D = 50 \text{ mA}$ )
  - $R_{DS(ON)} = 2.20 \Omega$  (max) (@ $V_{GS} = 4.5 \text{ V}$ ,  $I_D = 100 \text{ mA}$ )
- (3) Low leakage current
- (4) N-ch 2-in-1

## 3. Packaging and Internal Circuit



Start of commercial production

2024-04

### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ ) (Q1,Q2 Common)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	20	V
Gate-source voltage	$V_{GSS}$	$\pm 10$	
Drain current (Note 1)	$I_D$	250	mA
Drain current (pulsed) (Note 1)	$I_{DP}$	500	
Power dissipation (Note 2)	$P_D$	150	mW
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	$^\circ\text{C}$

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed  $150\text{ }^\circ\text{C}$ .

Note 2: Device mounted on an FR4 board. (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm ,Cu pad: 0.135 mm<sup>2</sup>  $\times$  6)

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the drain power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

### 5. Electrical Characteristics

#### 5.1. Static Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )(Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 5\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 0.08$	$\mu\text{A}$
		$V_{GS} = \pm 10\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 1$	
Drain cut-off current	$I_{DSS}$	$V_{DS} = 20\text{ V}, V_{GS} = 0\text{ V}$	—	—	0.08	V
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 1\text{ mA}, V_{GS} = 0\text{ V}$	20	—	—	
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = 1\text{ mA}, V_{GS} = -10\text{ V}$	12	—	—	
Gate threshold voltage (Note 2)	$V_{th}$	$V_{DS} = 3\text{ V}, I_D = 1\text{ mA}$	0.35	—	1.0	
Drain-source on-resistance (Note 3)	$R_{DS(ON)}$	$I_D = 100\text{ mA}, V_{GS} = 4.5\text{ V}$	—	1.65	2.20	$\Omega$
		$I_D = 50\text{ mA}, V_{GS} = 2.5\text{ V}$	—	2.16	3.02	
		$I_D = 20\text{ mA}, V_{GS} = 1.8\text{ V}$	—	2.66	4.05	
		$I_D = 10\text{ mA}, V_{GS} = 1.5\text{ V}$	—	3.07	5.60	
Forward transfer admittance (Note 3)	$ Y_{fs} $	$V_{DS} = 3\text{ V}, I_D = 100\text{ mA}$	0.14	0.28	—	S

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

Take this into consideration when using the device.

Note 3: Pulse measurement.

#### 5.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )(Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$	—	12	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	4.1	—	
Output capacitance	$C_{oss}$		—	5.5	—	
Switching time (turn-on time)	$t_{on}$	$V_{DD} = 10\text{ V}, I_D = 100\text{ mA},$ $V_{GS} = 0\text{ to }2.5\text{ V}, R_{GS} = 50\ \Omega$ Common source, See Chapter 5.3.	—	18	—	ns
Switching time (turn-off time)	$t_{off}$		—	36	—	

#### 5.3. Switching Time Test Circuit(Q1,Q2 Common)

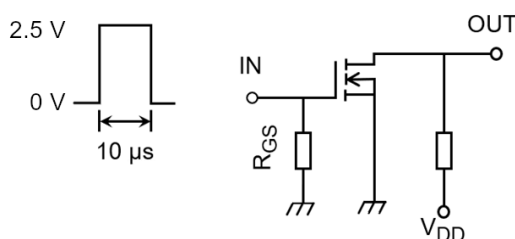


Fig. 5.3.1 Switching Time Test Circuit

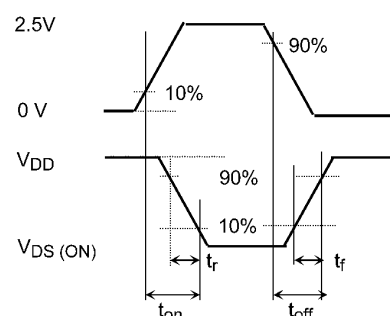


Fig. 5.3.2 Input Waveform/Output Waveform

#### 5.4. Source-Drain Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )(Q1,Q2 Common)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	$V_{DSF}$	$I_D = -250\text{ mA}, V_{GS} = 0\text{ V}$	—	-0.9	-1.2	V

Note 1: Pulse measurement.

## 6. Marking

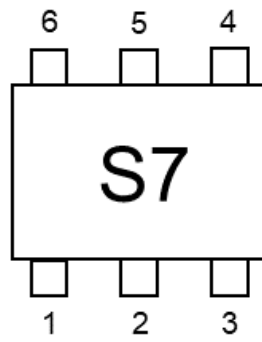


Fig. 6.1 Marking

### 7. Characteristics Curves (Note)

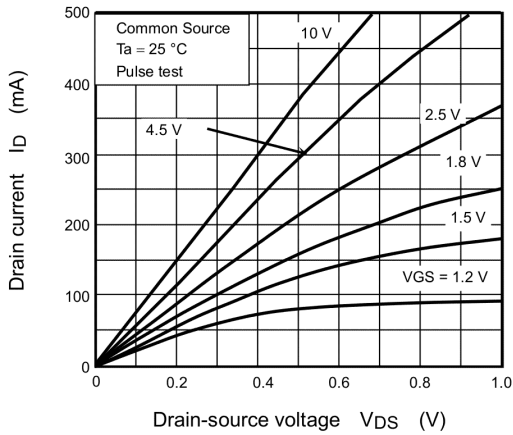


Fig. 7.1 ID - VDS

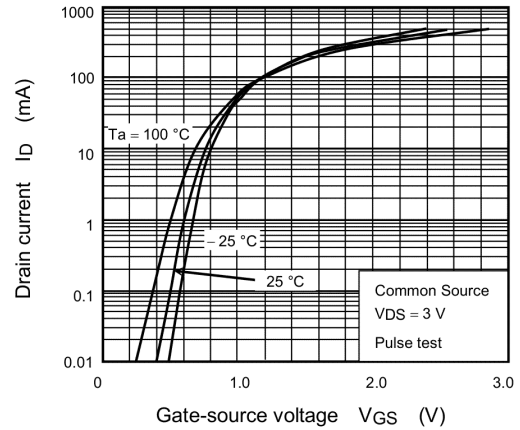


Fig. 7.2 ID - VGS

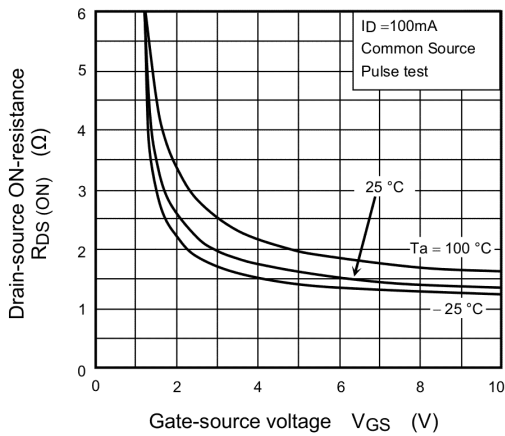


Fig. 7.3 RDS(ON) - VGS

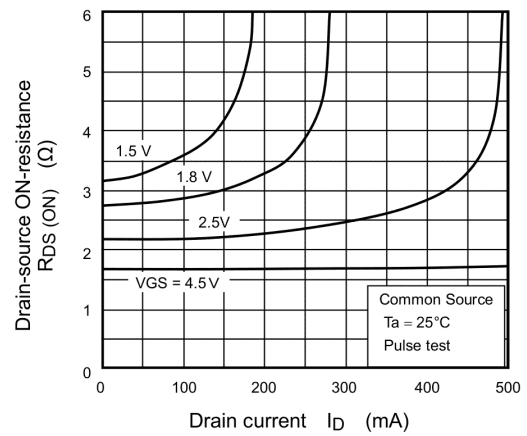


Fig. 7.4 RDS(ON) - ID

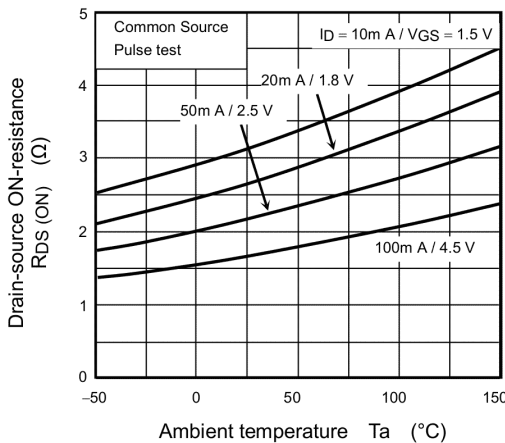


Fig. 7.5 RDS(ON) - Ta

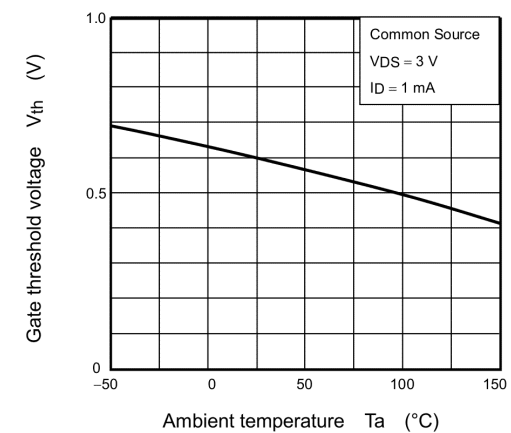
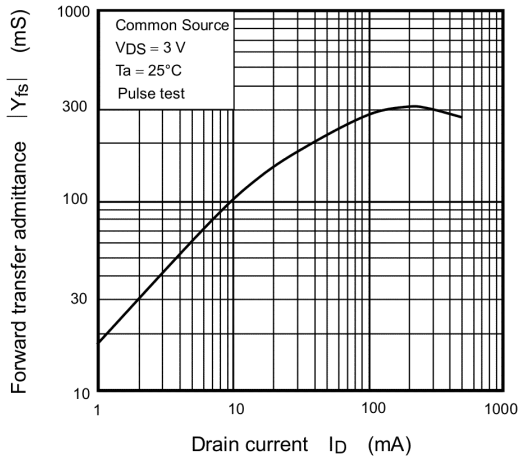
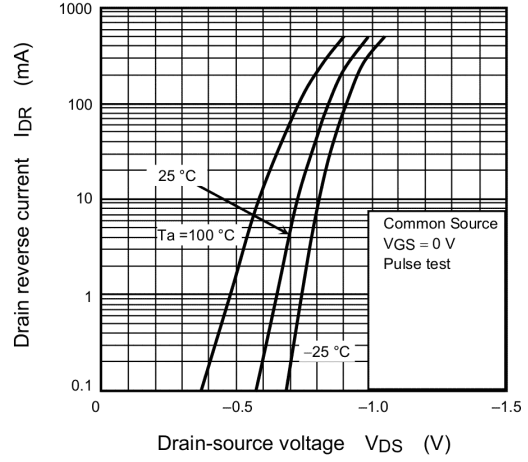


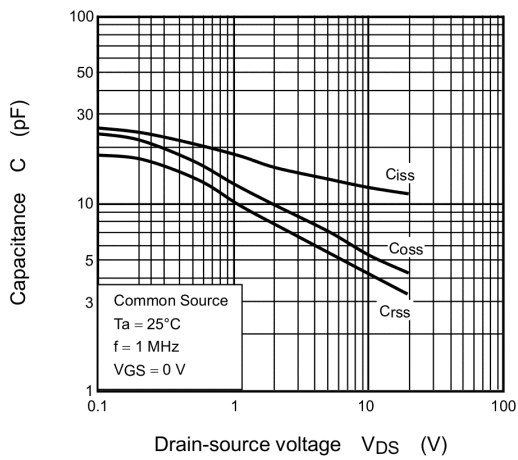
Fig. 7.6 Vth - Ta



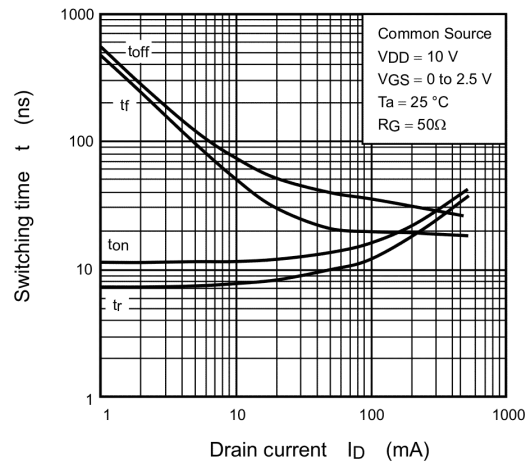
**Fig. 7.7**  $|Y_{fs}| - I_D$



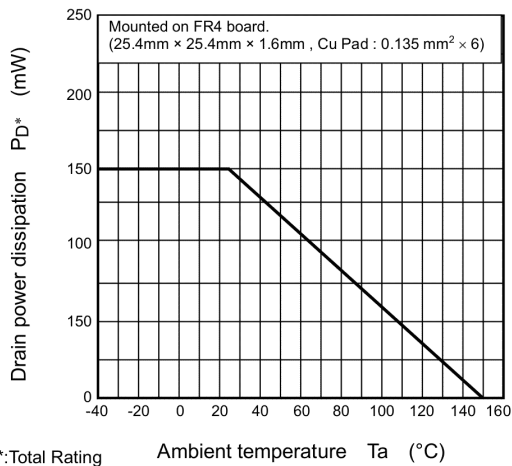
**Fig. 7.8**  $I_{DR} - V_{DS}$



**Fig. 7.9** C -  $V_{DS}$



**Fig. 7.10** t -  $I_D$



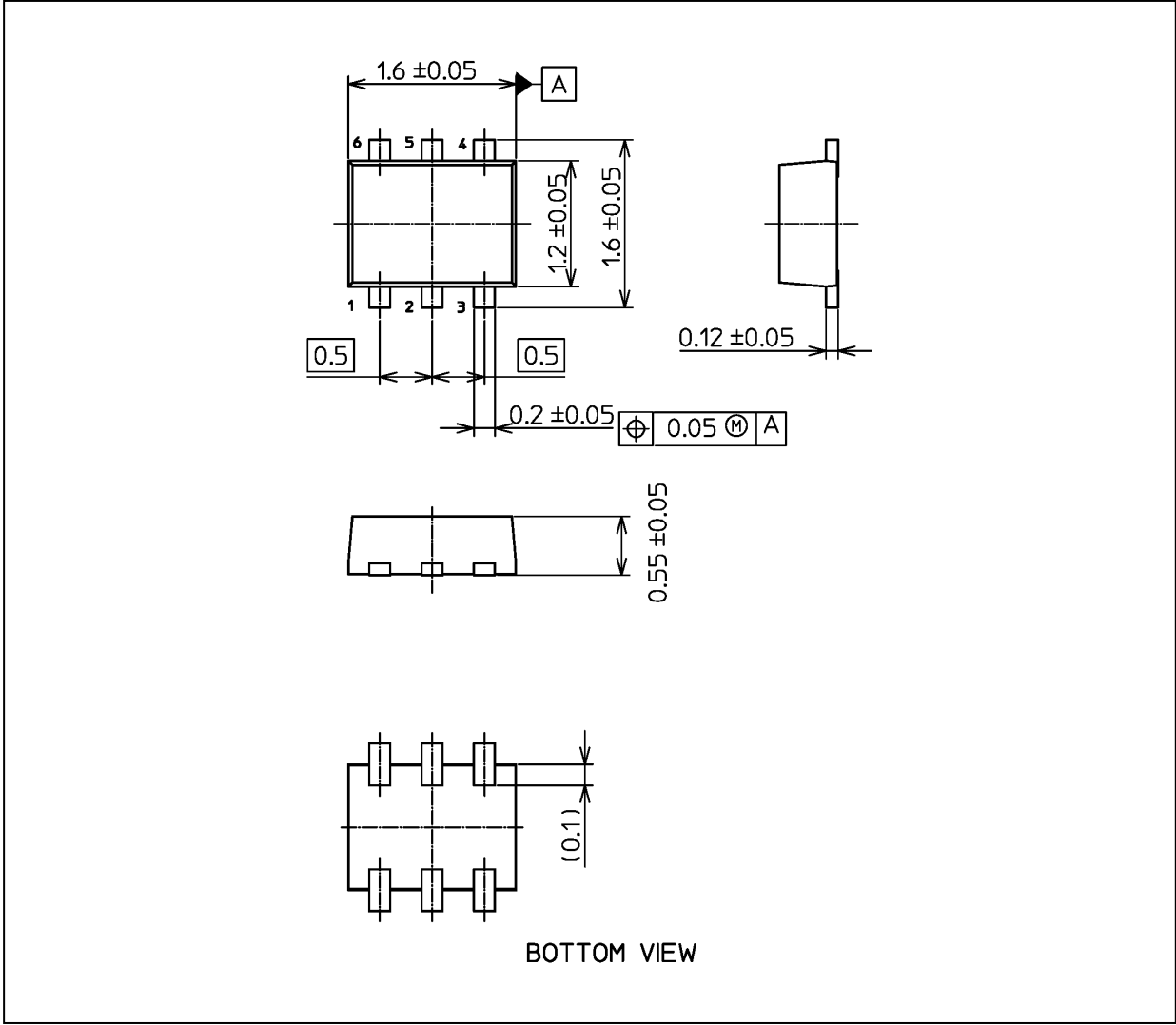
**Fig. 7.11**  $P_{D^*} - T_a$

\*:Total Rating

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 3.0 mg (typ.)

Package Name(s)
Nickname: ES6

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